

#### **Description**

The HXY20P03D uses advanced trench technology

to provide excellent R<sub>DS(ON)</sub>, low gate charge and

operation with gate voltages as low as 4.5V. This

device is suitable for use as a

Battery protection or in other Switching application.



TO252-2L

#### **General Features**

 $V_{DS} = -30V I_{D} = -20A$ 

 $R_{DS(ON)}$  < 42 m $\Omega$  @  $V_{GS}$ =10V



#### P-Channel MOSFET

#### **Application**

Battery protection

Load switch

Uninterruptible power supply

### **Package Marking and Ordering Information**

Product ID	Pack	Marking	Qty(PCS)
HXY20P03D	TO252-2L	20P03 XXX YYYY	2500

#### Absolute Maximum Ratings (T<sub>c</sub>=25<sup>°</sup>Cunless otherwise noted)

Symbol	Parameter	Rating	Units	
VDS	Drain-Source Voltage	-30	V	
VGS	Gate-Source Voltage	±25	V	
I <sub>D</sub> @T <sub>C</sub> =25°C	Continuous Drain Current, V <sub>GS</sub> @ 10V <sup>1</sup>	ous Drain Current, V <sub>GS</sub> @ 10V <sup>1</sup> -20		
I <sub>D</sub> @T <sub>C</sub> =100°C	Continuous Drain Current, V <sub>GS</sub> @ 10V <sup>1</sup>	) 10V <sup>1</sup> -15		
IDM	Pulsed Drain Current <sup>2</sup>	-50	А	
P <sub>D</sub> @T <sub>C</sub> =25°C	Total Power Dissipation <sup>4</sup>	29		
TSTG	Storage Temperature Range	-55 to 150	°C	
TJ	Operating Junction Temperature Range	-55 to 150	°C	
ReJA	Thermal Resistance Junction-ambient <sup>1</sup>	75 °C.		
R₀JC	Thermal Resistance Junction-Case <sup>1</sup>	4.32 °C/W		



## Electrical Characteristics (T<sub>A</sub>=25 ℃ unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Тр	Max.	Unit
BVDSS	Drain-Source Breakdown Voltage	VGS=0V , ID=-250uA	-30			V
∆BVDSS/∆TJ	BVDSS Temperature Coefficient	Reference to 25°C , ID=-1mA		22		V/°C
RDS(ON)	Static Drain-Source On-Resistance2	VGS=-10V , ID=-15A	32	38	42	mΩ
		VGS=-4.5V , ID=-10A	48	60	70	
VGS(th)	Gate Threshold Voltage	VGS=VDS , ID =-250uA	-1.0		-2.5	V
△VGS(th)	VGS(th) Temperature Coefficient			4.6		mV/°C
		VDS=-24V , VGS=0V ,			-1	
IDSS		TJ=25℃				
	-Drain-Source Leakage Current	VDS=-24V, VGS=0V,			-5	uA
		TJ=55°C				
IGSS	Gate-Source	VGS=±25V , VDS=0V			±100	nA
	LeakageCurrent					
gfs	Forward	VDS=-5V , ID=-15A		19		S
	Transconductance					
Rg	Gate Resistance	VDS=0V , VGS=0V , f=1MHz		13		
Qg	Total Gate Charge (-4.5V)			12.5		
Qgs	Gate-Source Charge	VDS=-15V , VGS=-4.5V , ID=-15A		5.4		nC
Qgd	Gate-Drain Charge	_		5		1
Td(on)	Turn-On Delay Time			4.4		
Tr	Rise Time	VDD=-15V , VGS=-10V , RG=3.3 ,		11.2		1
Td(off)	Turn-Off Delay Time	ID=-15A		34		ns
Tf	Fall Time			18		
Ciss	Input Capacitance			1345		
Coss	Output Capacitance	VDS=-15V , VGS=0V , f=1MHz		194		pF
Crss	Reverse Transfer Capacitance			158		†

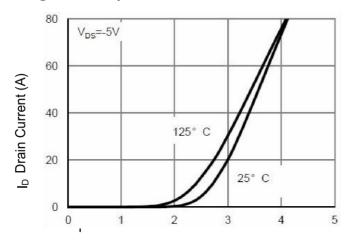
#### Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board,  $t \le 10$  sec.
- 3. Pulse Test: Pulse Width  $\leq 300 \mu s$ , Duty Cycle  $\leq 2\%$ .
- 4. Guaranteed by design, not subject to production

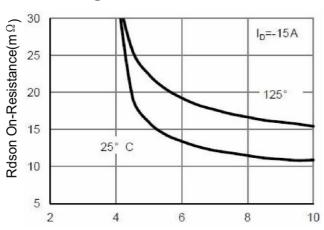


## **Typical Electrical and Thermal Characteristics**

#### **Figure 5 Output Characteristics**



Vgs Gate-Source Voltage (V)
Figure 7 Transfer Characteristics



Vgs Gate-Source Voltage (V)
Figure 9 Rdson vs Vgs

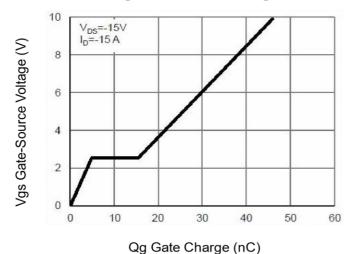


Figure 11 Gate Charge

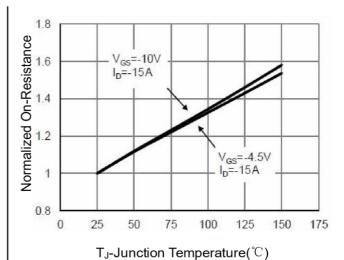
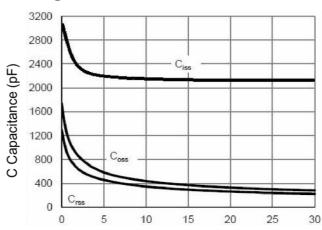
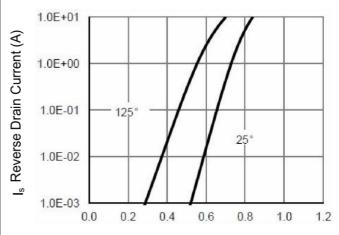


Figure 8 Drain-Source On-Resistance



Vds Drain-Source Voltage (V)
Figure 10 Capacitance vs Vds



Vsd Source-Drain Voltage (V)
Figure 12 Source- Drain Diode Forward



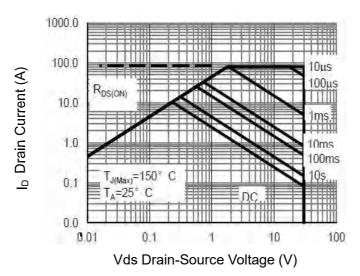
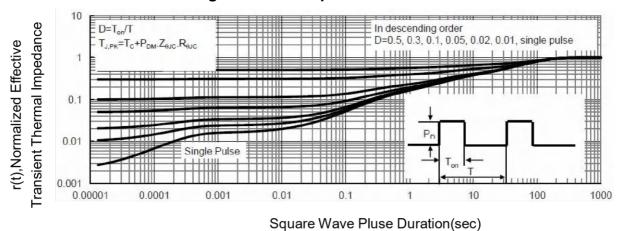


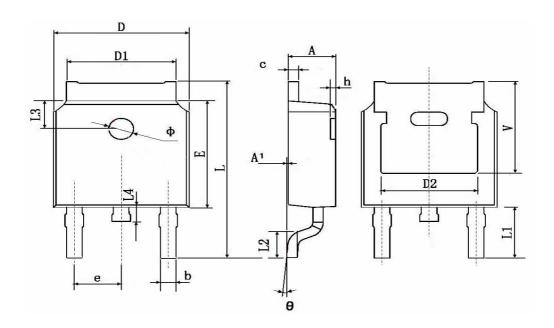
Figure 13 Safe Operation Area



**Figure 14 Normalized Maximum Transient Thermal Impedance** 



# **TO252-2L Package Information**



Symbol	Dimensions In Millimeters		Dimensions In Inches			
	Min.	Max.	Min.	Max.		
A	2.200	2.400	0.087	0.094		
A1	0.000	0.127	0.000	0.005		
b	0.660	0.860	0.026	0.034		
С	0.460	0.580	0.018	0.023		
D	6.500	6.700	0.256	0.264		
D1	5.100	5.460	0.201	0.215		
D2	4.83	4.830 TYP.		0.190 TYP.		
E	6.000	6.200	0.236	0.244		
е	2.186	2.386	0.086	0.094		
L	9.800	10.400	0.386	0.409		
L1	2.90	2.900 TYP.		0.114 TYP.		
L2	1.400	1.700	0.055	0.067		
L3	1.600 TYP.		0.063 TYP.			
L4	0.600	1.000	0.024	0.039		
Ф	1.100	1.300	0.043	0.051		
θ	0°	8°	0°	8°		
h	0.000	0.300	0.000	0.012		
V	5.350 TYP.		0.211 TYP.			



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